



200V/20A Silicon Carbide Schottky Diode

Features

- Positive temperature co-efficient
- Temperature-independent switching behavior
- Operation temperature up to $175\,^\circ\!\mathrm{C}$
- Zero reverse recovery current
- Zero forward recovery voltage

SC3S12020B

Description			
V _{RRM}	1200	V	
$I_{F,}$ T_{c} \leq	12.5	Α	
.,, ° 135℃	(per leg)		
Q _c	138	nC	

Benefits

- Uniploar rectifiers
- Essentially no switching losses
- Parallel devices without thermal runaway
- Reduction of heat sink requirements

Applications

- SMPS, PFC
- Motor driving, PV inverter, UPS, Wind engine, Rail traction, EV/HEV.



Part Number	Package	Marking	
SC3S12020B	TO-247-3 pin	12020B	

Maximum Ratings (Tc=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Value	Unit	
Repetitive Peak Reverse Voltage	V _{RRM}		1200	V	
Surge Peak Reverse Voltage	V _{RSM}		1200		
DC Blocking Voltage	V _{DC}		1200		
Continuous Forward Current	١ _F	T _c =25℃ T _c =135℃ T _c =155℃	25.9* 12.5* 10*	А	
Repetitive Peak Forward Surge Current	I _{FRM}	$T_{c}\text{=}25^{\circ}\text{C}$, tp=10ms , Half Sine Wave , D=0.3	50*	A	
Non-repetitive Peak Forward Surge current	I _{FSM}	$T_{C}\text{=}25^{\circ}\!\!\!\!\!^{\circ}\!\!\!^{\circ}$, tp=10ms , Half Sine Wave	100*	A	
Power Dissinction	D	T _C =25℃	141.5*	W	
Power Dissipation	P _{TOT}	T _C =110℃	62*	W	
Operation temperature	Tj		-55℃ to 175℃	°C	
Storage temperature	T _{stg}		-55℃ to 175℃	°C	
Mounting Torque		M3 Screw 6-32 Screw	1 8.8	Nm lbf-in	

Thermal Characteristics

Parameter	Symbol	Test condition	Value	Unit
			Typical	
Thermal resistance from Junction to Case	R_{thJC}		1.06* 0.53**	°C/W

Electrical Characteristics

Devementer	Symbol	Test Condition	Value		11	
Parameter	Symbol	Test condition	Тур.	Max.	Unit	
Forward valtage	VF	$I_{F}=10A, T_{j}=25^{\circ}C$	1.63	1.7	Ň	
Forward voltage	VF	$I_F = 10A, T_j = 175 °C$	2.55	3	V	
Devence evenent	1_	V_R =1200V, T_j =25°C	50	100		
Reverse current	I _R	V_R =1200V, T_j =175 °C	100	200	μΑ	
Total conceitive		V _R =800V, T _j =150°C				
Total capacitive charge	Qc	$Qc = \int_0^{VR} C(V)dV$	69	-	nC	
		$V_R=0V, T_j=25$ °C, f=1MHZ	770	790		
Total capacitance	С	V _R =400V, T _j =25°C, f=1MHZ	52	54	pF	
		V_R =800V, T_j =25°C, f=1MHZ	50	51		



RATING AND CHARACTERISTICS CURVES (SC3S12020B)

1) Forward characteristics

2)Reverse characteristics



3) Current Derating





4) Capacitance vs. Reverse voltage





TO-247



TT. 11	mm			
项目 标准值		Min	Max	
А	15.5	15.45	15.55	
В	20	19.9	20.1	
С	14.5	14.4	14.6	
D	3.5	3.3	3.6	
Е	3	2.95	3.05	
F	2	1.95	2.05	
G	1.3	1.2	1.4	
Н	5.5	5.4	5.6	
Ι	5	4.95	5.05	
J	0.6	0.58	0.62	
K	2.4	2.3	2.5	
L	2	1.9	2.1	
R	3.8	3.6	4	

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